

#### NPN 500mA 50V Digital Transistors (Bias Resistor Built-in Transistors)

Parameter	Value	
V <sub>CC</sub>	50V	
I <sub>C(MAX.)</sub>	500mA	
R <sub>1</sub>	2.2kΩ	
$R_2$	10kΩ	

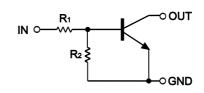
## ●Outline



#### Features

- 1) Built-In Biasing Resistors
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary PNP Types :DTB123YK
- 6) Lead Free/RoHS Compliant.

#### •Inner circuit



#### Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

#### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTD123YK	SMT3	2928	T146	180	8	3,000	F62

### ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Supply voltage	V <sub>cc</sub>	50	V
Input voltage	V <sub>IN</sub>	−5 to +12	V
Collector current	I <sub>C</sub> <sup>*1</sup>	500	mA
Power dissipation	P <sub>D</sub> *2	200	mW
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	−55 to +150	°C

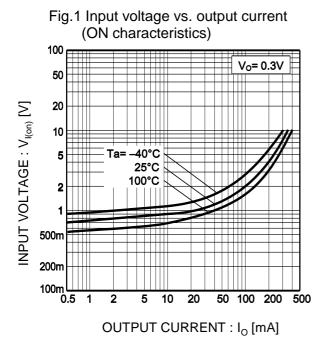
## ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = 5V, I_{O} = 100 \mu A$	-	-	0.3	V
	$V_{I(on)}$	$V_0 = 0.3V, I_0 = 20mA$	2.0	-	1	V
Output voltage	$V_{O(on)}$	$I_0 / I_1 = 50 \text{mA} / 2.5 \text{mA}$	-	0.1	0.3	V
Input current	I <sub>I</sub>	V <sub>I</sub> = 5V	1	-	3.6	mA
Output current	I <sub>O(off)</sub>	$V_{CC} = 50V, V_I = 0V$	1	-	0.5	μΑ
DC current gain	G <sub>I</sub>	$V_0 = 5V, I_0 = 50mA$	56	-	1	-
Input resistance	R <sub>1</sub>	-	1.54	2.2	2.86	kΩ
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	-	3.6	4.5	5.5	-
Transition frequency	f <sub>T</sub> *1	$V_{CE} = 10V, I_{E} = -50mA,$ f = 100MHz	-	200	-	MHz

<sup>\*1</sup> Characteristics of built-in transistor

<sup>\*2</sup> Each terminal mounted on a reference footprint

#### ●Electrical characteristic curves(Ta = 25°C)



(OFF characteristics) 10m 5m 2m OUTPUT CURRENT : Io [A] 1m 500µ Ta= 100°C 200μ 25°C 100μ -40°C 50μ 20μ 10μ 5μ 2μ 1μ∟ 0 1.5 2.0 3.0 INPUT VOLTAGE : V<sub>I(off)</sub>[V]

Fig.2 Output current vs. input voltage

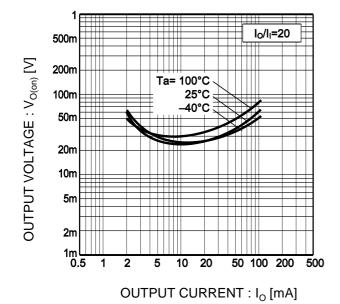
Fig.3 Output current vs. output voltage I<sub>i</sub>= 5.0mA 4.5mA 4.0mA 500 3.5mA 400 3.0mA OUTPUT CURRENT : Io [mA] 2.5mA GAIN 300 2.0mA CURRENT 1.5mA 200 100 0.5mA Ta=25°C 0 0 10 OUTPUT VOLTAGE : Vo [V]

1k
500
Ta= 100°C
25°C
-40°C
100
50
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CUTPUT CURRENT : I<sub>O</sub> [mA]

Fig.4 DC current gain vs. output current

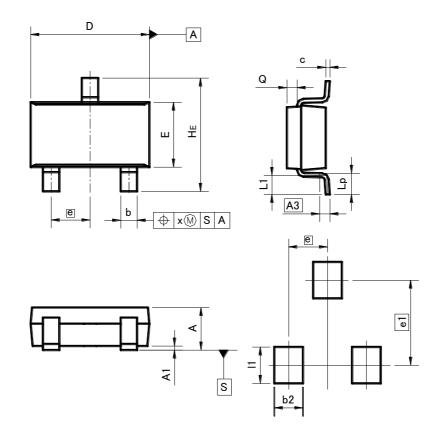
## ●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output voltage vs. output current



## ●Dimensions (Unit:mm)

### SMT3



#### Patterm of terminal position areas

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.00	1.30	ı	0.051	
<b>A</b> 1	0.00	0.10	0	0.004	
A3	0.25		0.01		
b	0.35	0.50	0.014	0.02	
С	0.09	0.25	0.004	0.01	
D	2.80	3.00	0.11	0.118	
E	1.50	1.80	0.059	0.071	
е	0.95		0.04		
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.20	0.30	0.008	0.012	
х		0.10	_	0.004	
у	_	0.10	_	0.004	

DIM	MILIMI	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
e1	2.10		0.08		
b2		0.60	-	0.024	
11	-	0.90	-	0.035	

Dimension in mm/inches

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